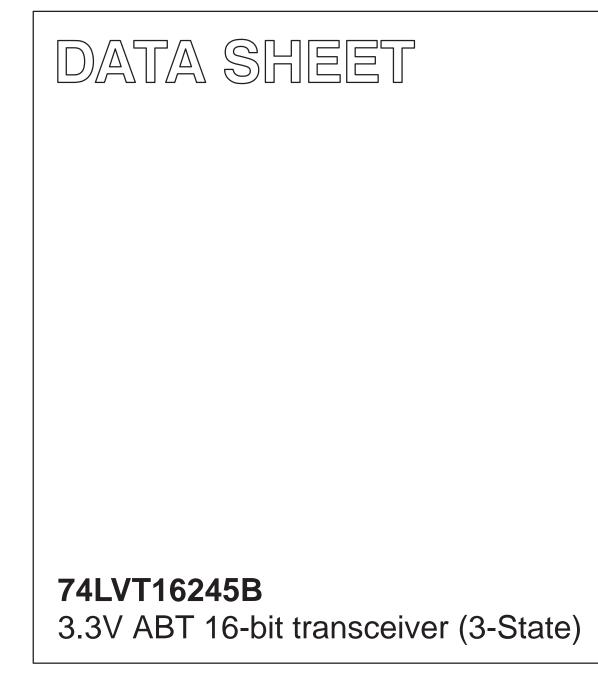
INTEGRATED CIRCUITS



Pproduct specification Supersedes data of 1994 May 23 IC23 Data Handbook 1998 Feb 19





74LVT16245B

FEATURES

- 16-bit bidirectional bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

QUICK REFERENCE DATA

DESCRIPTION

The 74LVT16245B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	$C_L = 50 pF;$ $V_{CC} = 3.3V$	1.9	ns
C _{IN}	Input capacitance DIR, OE	V _I = 0V or 3.0V	3	pF
C _{I/O}	I/O pin capacitance	V _{I/O} = 0V or 3.0V	9	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	70	μΑ

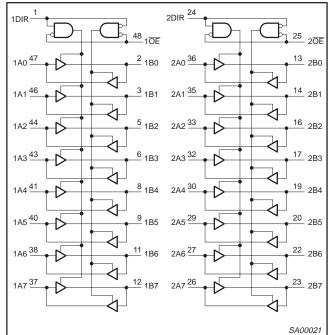
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16245B DL	VT16245B DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16245B DGG	VT16245B DGG	SOT362-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 24	nDIR	Direction control input
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	nA0 – nA7	Data inputs/outputs (A side)
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	nB0 – nB7	Data inputs/outputs (B side)
25, 48	n <mark>OE</mark>	Output enable input (active-Low)
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

LOGIC SYMBOL

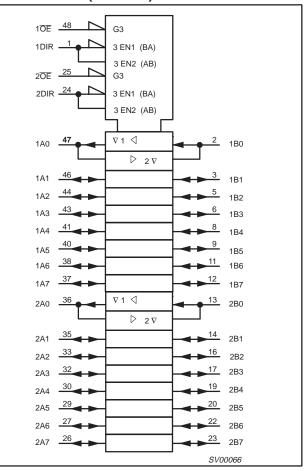


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PIN CONFIGURATION

1DIR 1	48	1 0E
1B0 2	47	1A0
1B1 3	46	1A1
GND 4	45	GND
1B2 5	44	1A2
1B3 6	43	1A3
V _{CC} 7	42	V _{CC}
1B4 8	41	1A4
1B5 9	40	1A5
GND 10	39	GND
1B6 [11	38	1A6
1B7 12	37	1A7
2B0 13	36	2A0
2B1 14	35	2A1
GND 15	34	GND
2B2 16	33	2A2
2B3 17	32	2A3
V _{CC} [18	31	V _{CC}
2B4 19	30	2A4
2B5 20	29	2A5
GND 21	28	GND
2B6 22	27	2A6
2B7 23	26	2A7
2DIR 24	25	2 0E
	SW00061	

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INP	UTS	INPUTS/OUTPUTS		
nOE	nDIR	nAx	nBx	
L	L	nAx = nBx	Inputs	
L	Н	Inputs	nBx = nAx	
Н	Х	Z	Z	

H = High voltage level

= Low voltage level L

X = Don't care Z = High Impedance "off" state

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ABSOLUTE MAXIMUM RATINGS^{1,2}

SYMBOL	PARAMETER CONDITIONS		RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I _{OUT} D	DC output current	Output in Low state	128	
		Output in High state	-64	— mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBUL	FARAIMEIER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Input voltage		0.8	V
I _{ОН}	High-level output current		-32	mA
I _{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		64	
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT	
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.85	-1.2	V
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$		V _{CC} -0.2	V _{CC}		
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		
		V _{CC} = 2.7V; I _{OL} = 100µA			0.07	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	V
		V _{CC} = 3.0V; I _{OL} = 32mA			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}$	Quality		0.1	±1	
	V _{CC} = 0 or 3.6V; V _I = 5.5V	Control pins		0.1	10	1	
I _I	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V			0.1	20	μA
		$V_{CC} = 3.6V; V_{I} = V_{CC}$	I/O Data pins ⁴		0.5	10	
		$V_{CC} = 3.6V; V_{I} = 0$	1		0.1	-5	
I _{OFF}	Output off current	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$	•		0.1	±100	μA
	Due Hald summer	$V_{CC} = 3V; V_{I} = 0.8V$		75	135		
I _{HOLD}	Bus Hold current A or B outputs ⁶	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-135		μA
	·	$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V	V _O = 5.5V; V _{CC} = 3.0V		75	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} ; OE/OE = Don't care			40	±100	μΑ
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or V_{CC} , $I_O = 0$			0.07	0.12	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$			4.7	6	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND \text{ or } V_{CC} I_O = 0^5$			0.07	0.12	
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	Ι,		0.1	0.2	mA

NOTES:
All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.
I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
This is the bus hold overdrive current required to force the input to the opposite logic state.

6. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

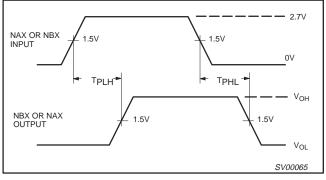
			LIMITS				UNIT
SYMBOL PARAMETER		WAVEFORM	V _{CC} = 3.3V +0.3V			V _{CC} = 2.7V	
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	1	1.0 1.0	1.9 1.7	3.3 3.3	3.5 3.5	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	2.8 2.8	4.5 4.1	5.3 5.1	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.5 1.5	3.2 3.0	5.1 4.6	5.7 4.6	ns

NOTE:

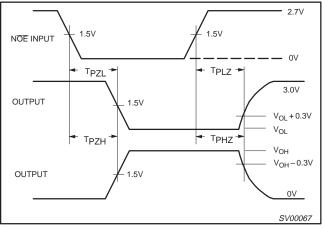
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25^{\circ}C.

AC WAVEFORMS

 V_{M} = 1.5V, V_{IN} = GND to 2.7V



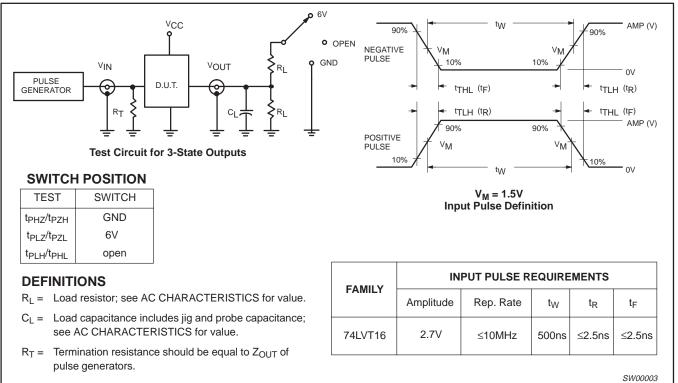
Waveform 1. Input to Output Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

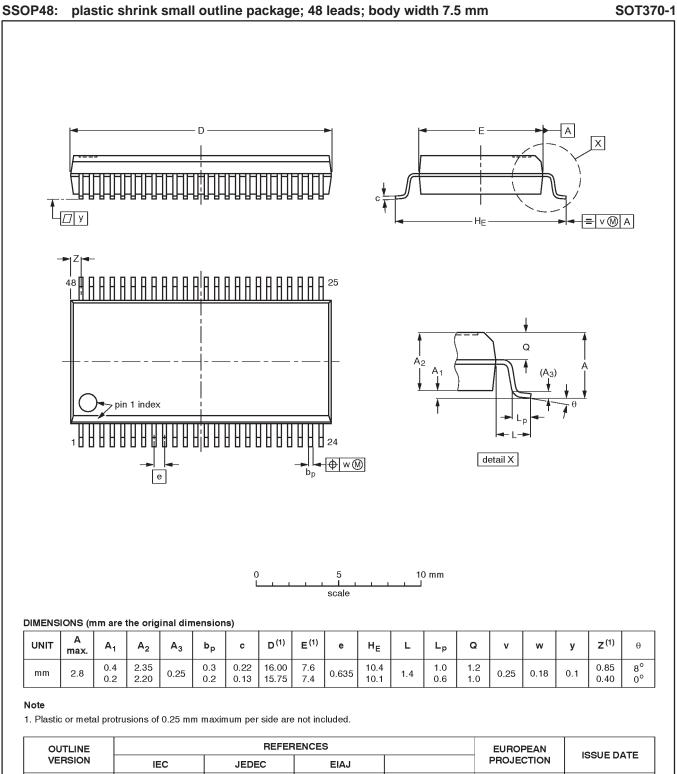
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TEST CIRCUIT AND WAVEFORMS

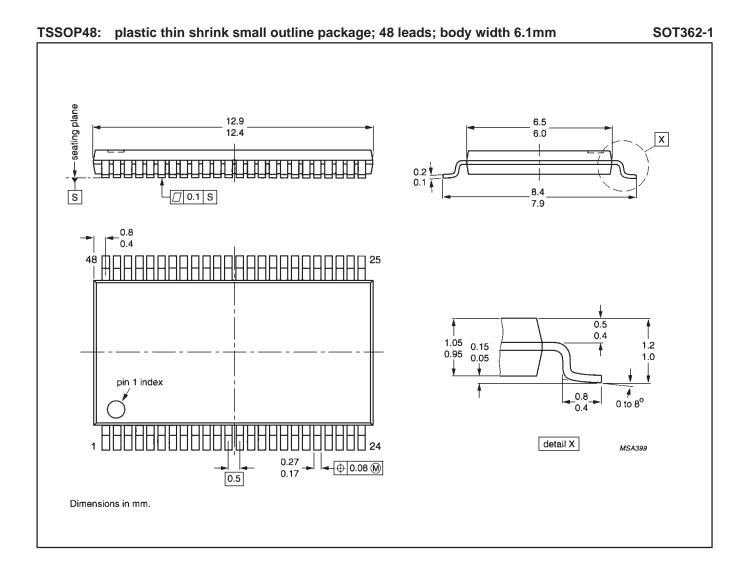


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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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